Product Change Notice



PCN: PCN_KVR24R17S4_8I_C1

Date: July 1, 2016

Kingston Technology Company 17600 Newhope Street Fountain Valley, CA 92708 USA

Type of Change: Build (BOM) Phase Out for End of Life

Product(s) Affected: KVR24R17S4/8I

KVR24R17S4K4/32I (Kit of 4)

Qualified Build: 9965589-017.D00G (Hynix A Die) – Phase Out

9965589-031.D01G (Micron B Die) - Qualifying, ETA 8/1/16

Product Description: 8GB DDR4-2400 Registered DIMM CL17 1Rx4 1.2V Intel Certified

Description of Change: Build 9965589-017.D00G using Hynix A Die is being phased out and replaced by a next

generation DRAM component. Alternate build 9965589-031.D01G using Micron B Die is

being qualified and is estimated to be available on 8/1/2016.

Target EOL Date: September 29, 2016